



#### **Product Summary**

BVDSS	Rds(on) Max	I <sub>D</sub> Max Ta = +25°C
	25mΩ @ V <sub>GS</sub> = 4.5V	6.8A
20V	29mΩ @ V <sub>GS</sub> = 2.5V	5.5A

#### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  yet maintain superior switching performance, which make it ideal for high-efficiency power management applications.

- Backlighting
- Power-Management Functions
- DC-DC Converters
- Motor Control
  - ESD-Protected Gate



Top View

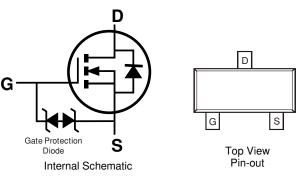
- Features and Benefits
- Low On-Resistance
- Low-Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

N-CHANNEL ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN2024UQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ©3
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2024UQ-7	SOT23	3,000/Tape & Reel
DMN2024UQ-13	SOT23	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/guality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**

05U	ΥM

 $\begin{array}{l} 05U = \mbox{Product Type Marking Code} \\ YM = \mbox{Date Code Marking} \\ Y \mbox{ or } \overline{Y} = \mbox{Year (ex: H = 2020)} \\ M = \mbox{Month (ex: 9 = \mbox{September)}} \end{array}$ 

Date Code Key

Date Obuc Key												
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н		J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit		
Drain-Source Voltage		VDSS	20	V		
Gate-Source Voltage	V <sub>GSS</sub>	±10	V			
	Steady	T <sub>A</sub> = +25°C		6.8	•	
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	State	TA = +70°C	ID	5.5	A	
Maximum Continuous Body Diode Forward Curre	ent (Note 6)	ls	2.2	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle =	1%)		IDM	45	А	

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	159	°C/W
Total Power Dissipation (Note 6)		PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	92	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

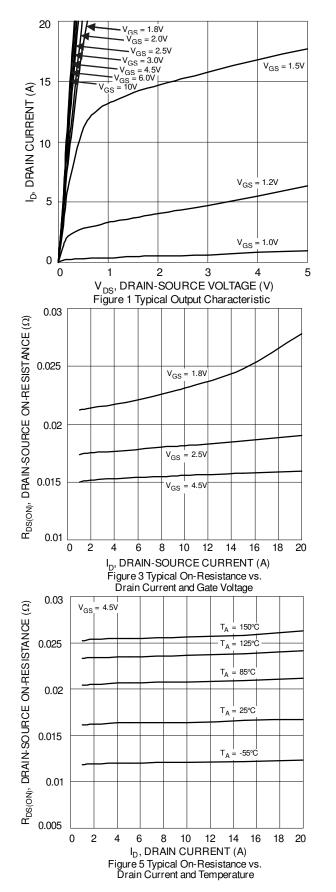
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage		BVDSS	20	-	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> =	+25°C	IDSS	—		1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage		lgss	—		±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage		V <sub>GS(TH)</sub>	0.5	_	0.9	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
				16	25		$V_{GS} = 4.5V, I_D = 6.5A$
Static Drain-Source On-Resistance		RDS(ON)	—	18.5	29	mΩ	$V_{GS} = 2.5V, I_{D} = 5.5A$
				23	36		$V_{GS} = 1.8V, I_{D} = 3.5A$
Diode Forward Voltage		Vsd	—	0.8	1.2	V	$V_{GS} = 0V, I_D = 5A$
DYNAMIC CHARACTERISTICS (Note 8)					-	-	
Input Capacitance		Ciss	—	647	—	pF	
Output Capacitance		Coss	—	78	_	pF	Vps = 10V, Vgs = 0V f = 1.0MHz
Reverse Transfer Capacitance		Crss	—	38	—	pF	
Gate Resistance		Rg	—	400	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge		Qg	—	6.5	—	nC	
Gate-Source Charge		Qgs	—	1.1	—	nC	$V_{GS} = 4.5V, V_{DS} = 10V, I_D = 6.5A$
Gate-Drain Charge		Qgd	—	1.7	—	nC	
Turn-On Delay Time		td(on)	_	98	—	ns	
Turn-On Rise Time		tR	—	140	—	ns	$V_{DS} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time		td(OFF)	—	1024	—	ns	$R_L=10\Omega,\ R_g=6\Omega,\ I_D=1A$
Turn-Off Fall Time		tF	—	434	—	ns	
Reverse Recovery Time		trr	—	245	—	ns	IF = 1.0A, di/dt = 100A/µs
Reverse Recovery Charge		Qrr	—	149	—	nC	IF = 1.0A, di/dt = 100A/µs

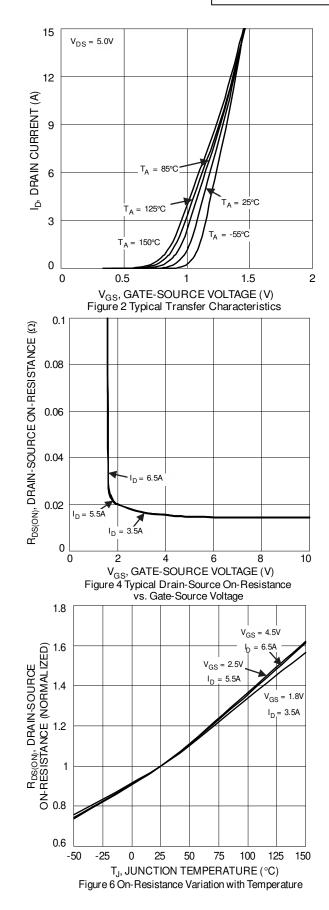
Notes:

Device mounted on FR-4 PCB with minimum recommended pad layout.
 Device mounted on 1" x 1" FR-4 PCB with high-coverage 2oz copper, single sided.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

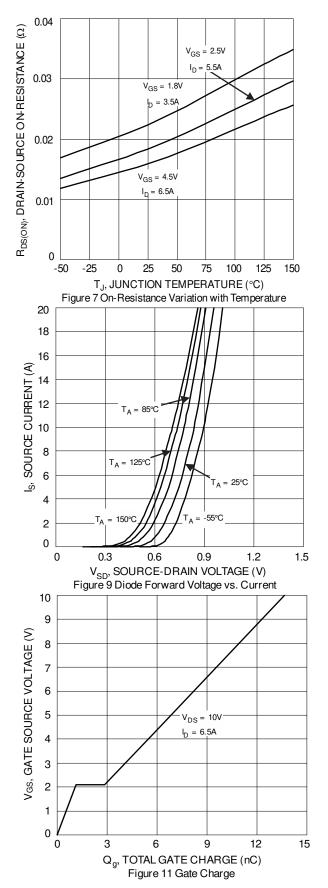


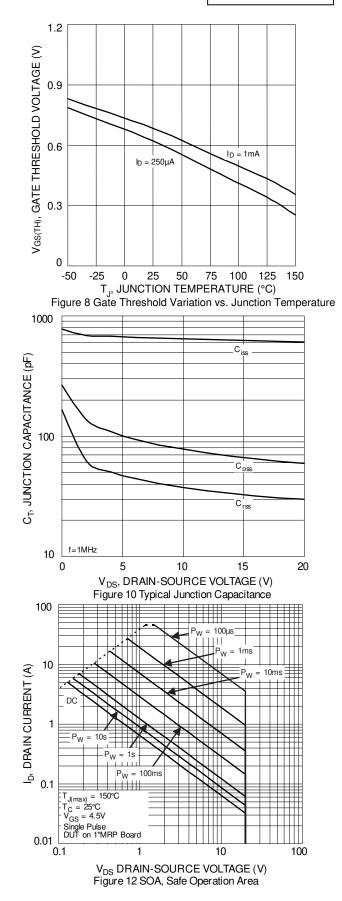
#### **DMN2024UQ**



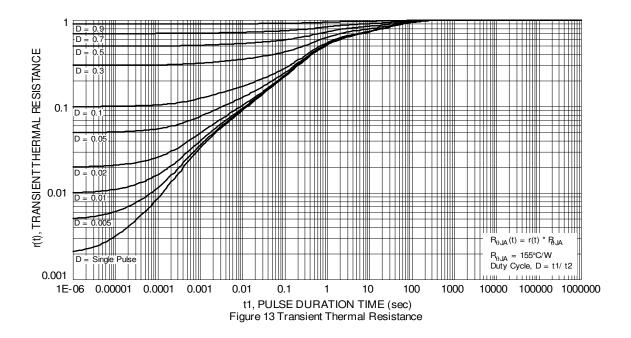








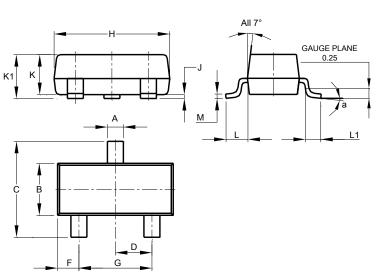






#### **Package Outline Dimensions**

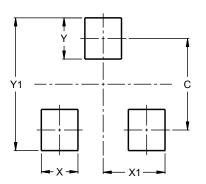
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
н	2.80	3.00	2.90
J	0.013	0.10	0.05
К	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а	0°	8°	
All	Dimens	ions in	mm

#### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

# SOT23



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